



# 21st RD50 Workshop (CERN)

## Friday 16 November 2012

### Irradiation Facilities, 3D and Pixel Detectors (joined with ATLAS PPS) (09:00 - 12:40)

-Conveners: **Giulio Pellegrini; Daniel Muenstermann**

time	[id] title	presenter
09:00	[13] Non uniform irradiation of CNM 3D sensors for AFP	MICELLI, Andrea
09:20	[18] Scribe-Cleave-Passivate (SCP) Slim Edge Technology for Silicon Sensors	FADEYEV, Vitaliy
09:40	[23] Progress on the Low Resistance Strip Sensors and Slim Edges Combined RD50 Experiment	BENITEZ CASMA, Victor Hugo
10:00	[20] Characterization of thin high irradiated n-in-p planar pixel sensor	TERZO, Stefano
10:20	[9] Characterization of active edge planar pixels produced at VTT	MACCHIOLO, Anna
10:40	Coffee Break	
11:10	[37] First experience with radiation-hard active sensors in 180 nm HV CMOS technology	MUENSTERMANN, Daniel
11:30	[51] Study of the behaviours of silicon sensor structures, before and after irradiation	UNNO, Yoshinobu
11:50	[1] The Birmingham Irradiation Facility	FRENCH, Richard
12:10	[49] RD50 - New structures discussion session	PELLEGRINI, Giulio